

Probing Interfacial Contact via MEMS-based Microinstrumentation

Roya Maboudian

**Department of Chemical & Biomolecular
Engineering
Berkeley Sensor and Actuator Center (BSAC)
Center of Integrated Nanomechanical Systems
(COINS)
Center for Interfacial Engineering of MEMS (CIE)**

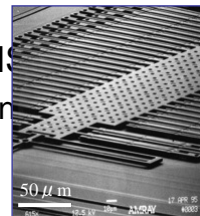


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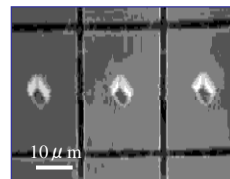


Outline of the Talk

- Surface-related reliability issues in MEMS
 - adhesion (stiction); friction; wear; corrosion
- Test structure development
- Surface modifications
 - self-assembled monolayer
 - hard inorganic coatings
- Environmental effects
 - fluidic; temperature; relative humidity

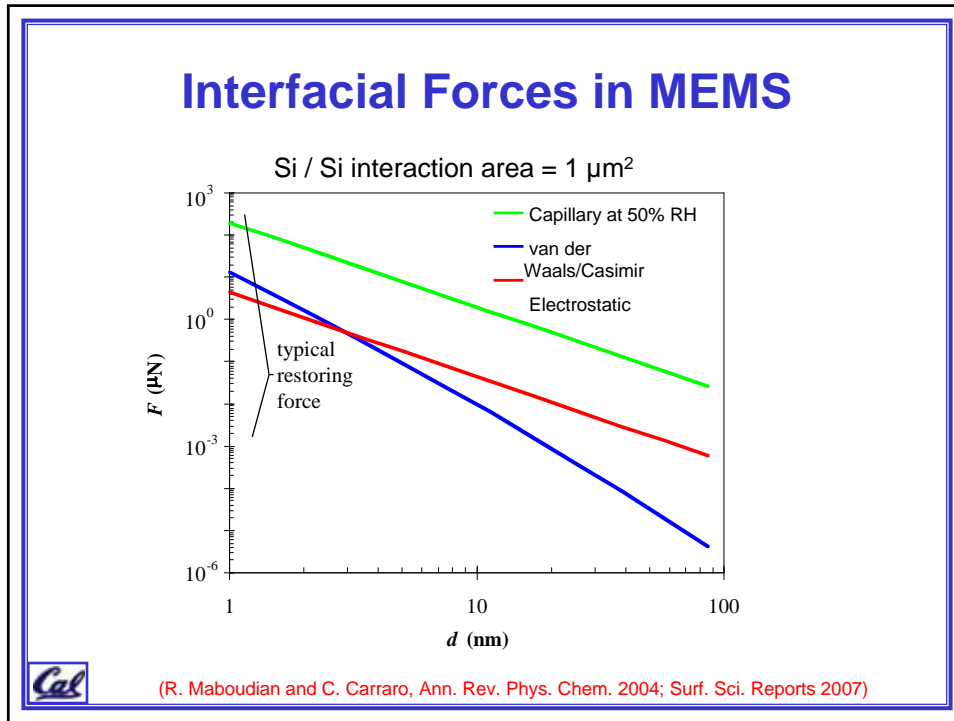


Accelerometer



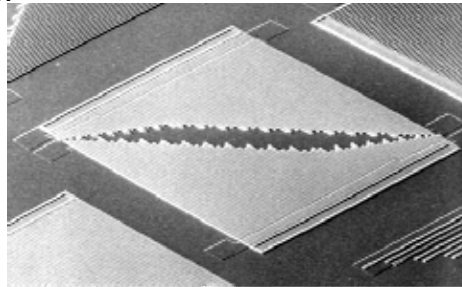
Micromirror Display





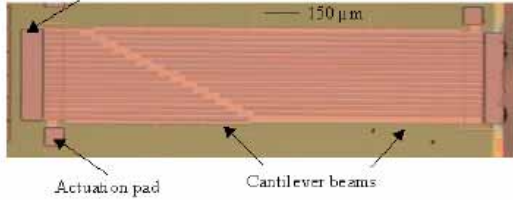
Instrumentation Needs

- MEMS-based instruments can provide information on:
 - material systems of interest to MEMS following the appropriate processing sequence;
 - length scales not easily accessible with other techniques.

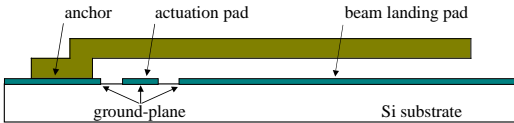


Adhesion Micro-instrument: Cantilever Beam Array


Top View



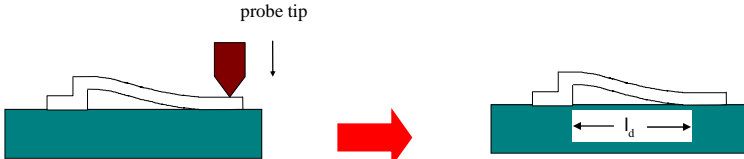
Side View



$$l_d \approx l_c + \sum_{i=min}^{i=max} [1-P(l_i)]\Delta l \quad l_c = l_{min} - \Delta l \quad \begin{matrix} l_d = \text{detachment length} \\ P(l_i) = \text{sticking probability} \end{matrix}$$




Adhesion Measurement



Beam analysis yields:

$$W = \frac{3}{8} \frac{Et^3 h^2}{l_d^4}$$

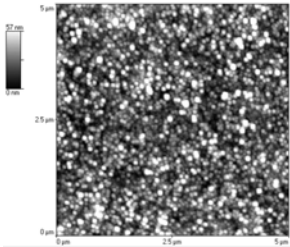
W = work of adhesion
 E = Young's modulus
 t = thickness of the beam
 h = height above the surface
 l_d = detachment length



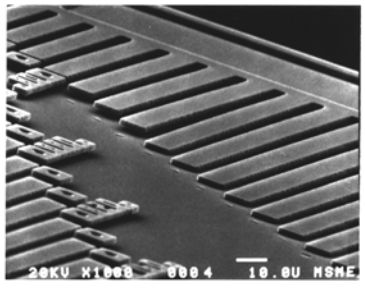
[C. H. Mastrangelo, *Tribology Letters* '98]

In-use Adhesion: SiO₂-coated Surfaces

5x5 μm²

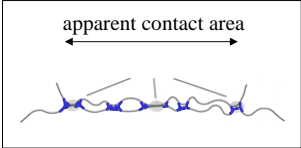


RMS = 12 nm




Increasing length

apparent contact area




At 50% relative humidity:
 $l_d = 110 \mu\text{m}$ → $W = 20 \text{ mJ/m}^2$




Self Assembled Monolayers (SAM)


End group



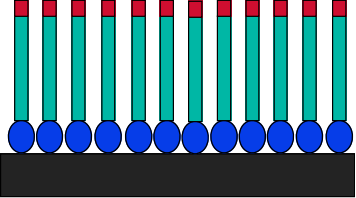
Alkyl chain



Surface active head group

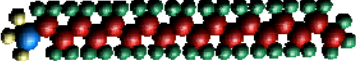


→



- Form well-packed films
- Modify surface properties

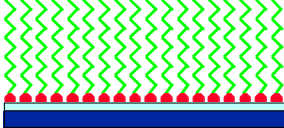
CH3-(CH2)17-SiCl3: OTS



SAM Formation


→

close-packed alkyl chains



Silicon substrate

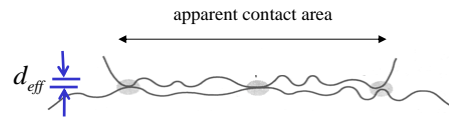
$\theta_{\text{H}_2\text{O}}$ on Si(100) ~ 110°



Characteristics of OTS-Coated MEMS

- Work of adhesion: $W = 0.012 \pm 0.004 \text{ mJ/m}^2$
- cf., $\sim 20 \text{ mJ/m}^2$ for oxide-coated surfaces
- W unchanged even in 99% relative humidity
- cf., 140 mJ/m^2 for oxide-coated surfaces

$$W_{vdW} = \frac{A}{12\pi d_{eff}^2} \approx 0.01 \text{ mJ/m}^2$$



- Static friction coefficient: $\mu_s = 0.07 \pm 0.005$
- cf., ~ 1 for oxide-coated surfaces



Effects of Repetitive Contact

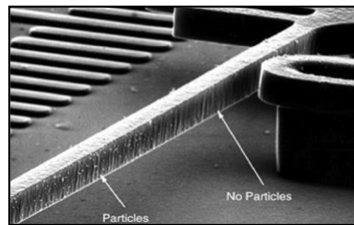


Accelerated Life-time Testing

Motivation:

- MEMS devices designed for repeated contact often fail due to wear;
- It is desirable to understand and predict the failure mechanisms.

Sliding sidewall-contact microinstrument



(W.R.Ashurst et. al. *Tribology Letters* 2004)



Microinstrument Design

Planned Operation

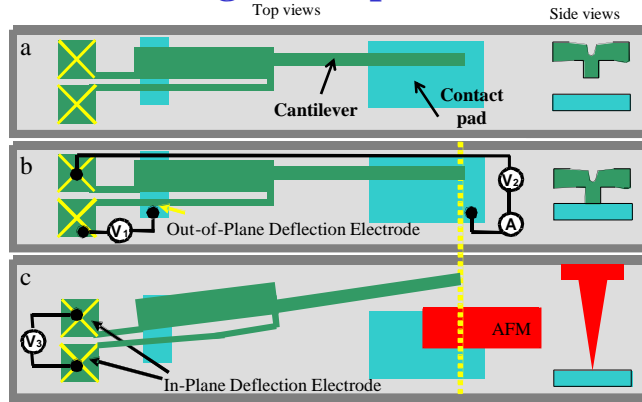
1. Cyclic contact between two MEMS surfaces
2. Separation of the surfaces
3. **In situ** Analysis of surfaces
4. **Repeat** steps 1-3

Design Constraints

1. Surfaces must be capable of repeated contact (**out-of-plane**)
2. Surfaces must be capable of *temporary* separation at large enough distances to permit analysis (**in-plane**)



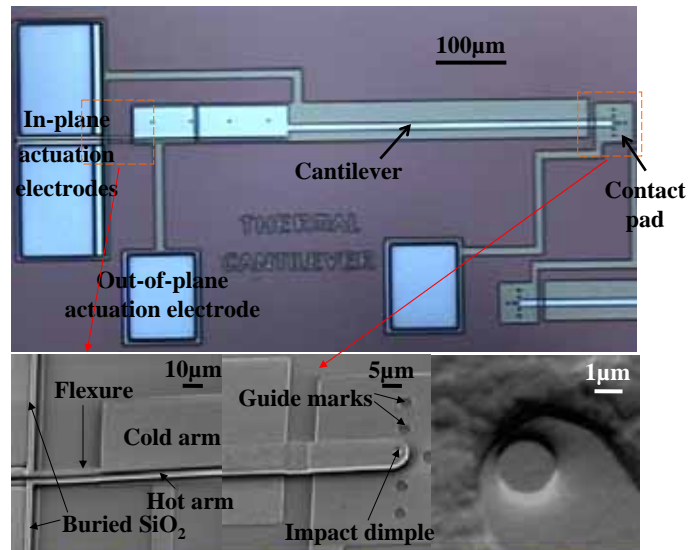
2-Axis MEMS Deflecting Cantilever (2AM-DC): design and operation



- Out-of-plane electrode is biased with respect to cantilever (V_1) to induce cantilever-substrate contact at distal end of cantilever
- Voltage V_2 applied between contact pad and cantilever and current measured.
- Cantilever is displaced in-plane with bias V_3 , allowing interrogation of contact region.



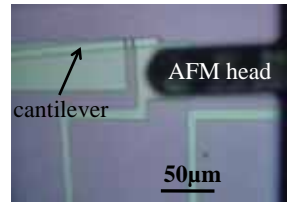
2AM-DC Microinstrument



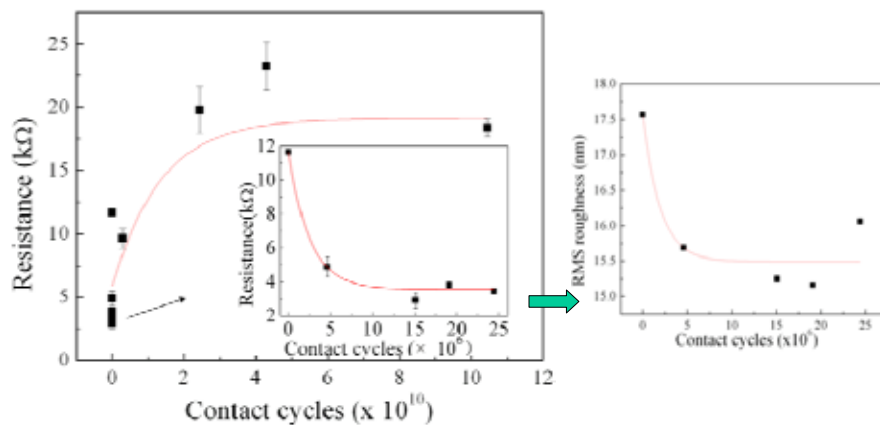
Interrogation Methodologies

Evolution in contact region probed
via:

- I-V measurements: Contact resistance
- AFM/KPFM: Surface topography, surface potential
- Scanning Auger electron spectroscopy: Chemical composition map

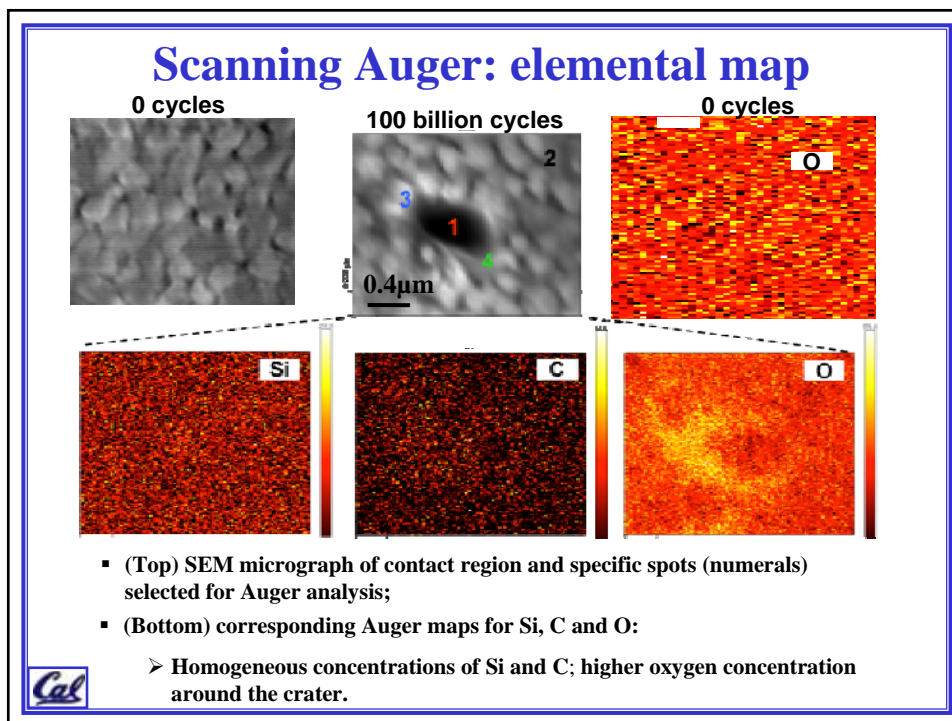
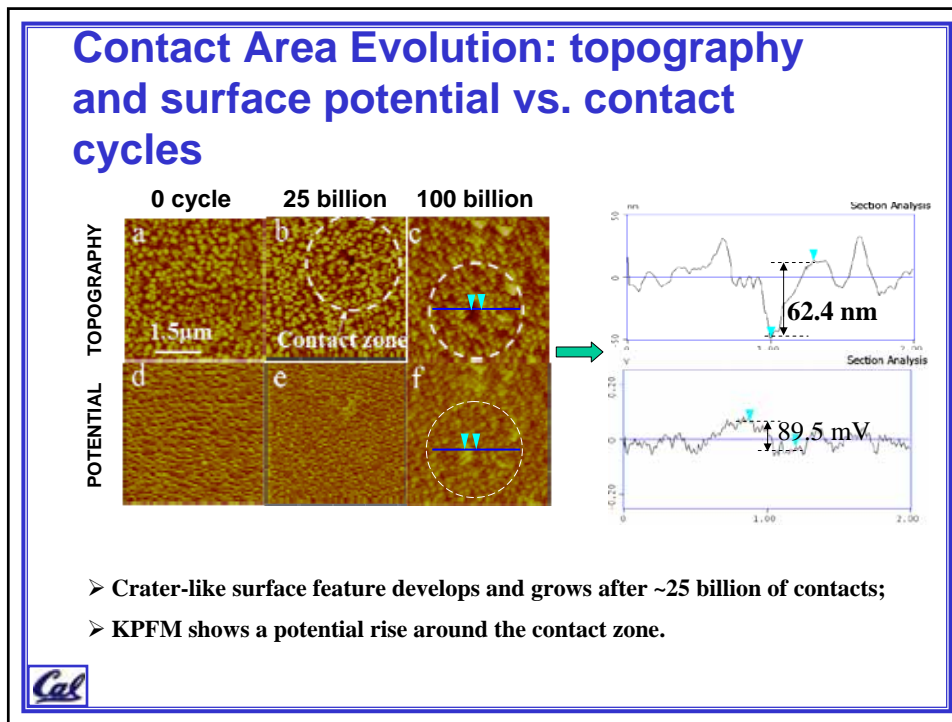


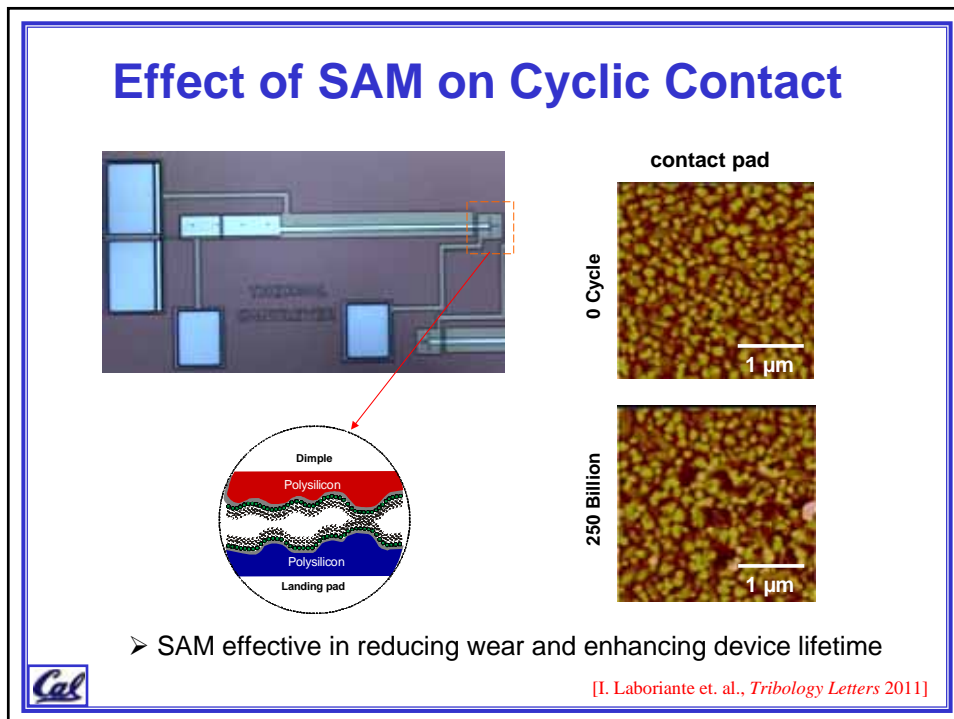
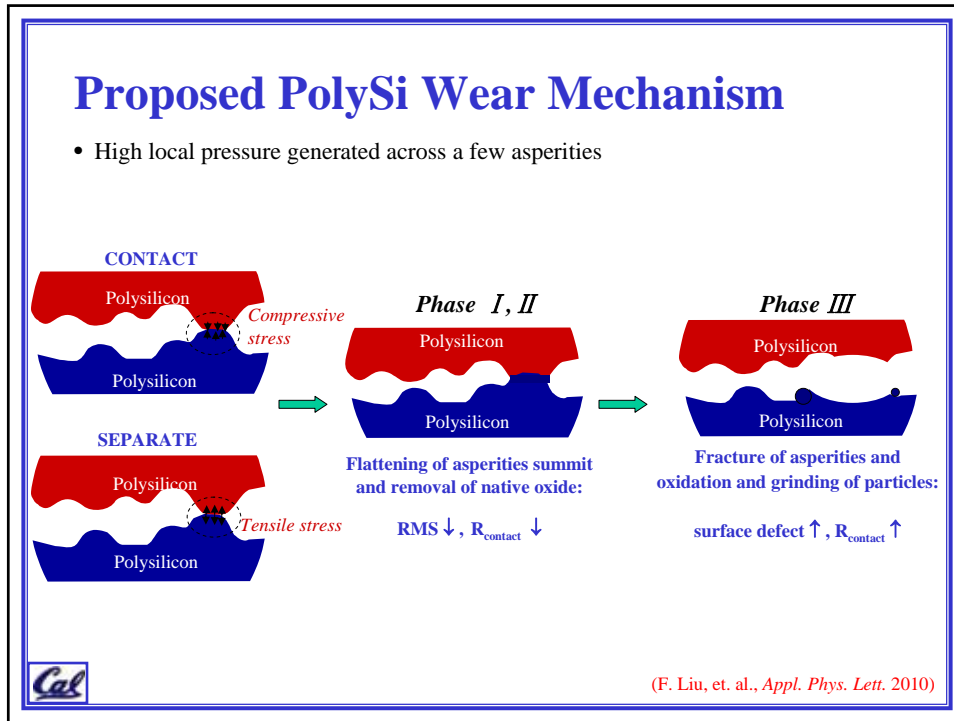
Contact Resistance Evolution



- Contact resistance ↓ during first tens of millions of impacts; then ↑ with increased contact cycles.







Effects of Relative Humidity in Presence of High Electric Field



Effect of Relative Humidity

- Ubiquitous presence of water vapor makes the study of relative humidity (RH) effects on the performance and reliability of M/NEMS devices crucial.
- Due to reduced dimensions, M/NEMS devices operate under high fields ($> 10^6$ V/m).
- Combination of relative humidity and electric field during device operation results in electrochemical reactions affecting the life time of M/NEMS devices.

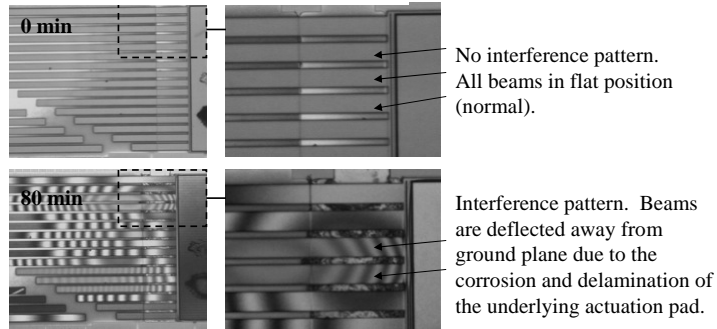


Life-time Testing

- ❑ Effect of Positive Actuation Voltage
 - beams begin to deflect upwards;
 - observed for relative humidity > 55 %

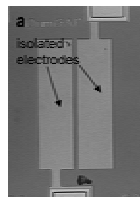
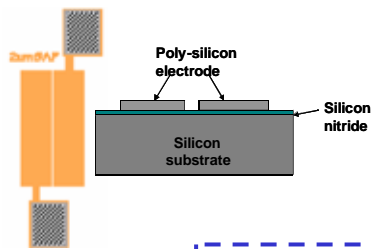


$V_{\text{actuation}} = +100 \text{ V}$; RH = 97%



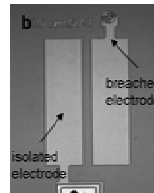
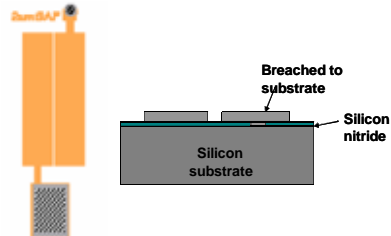
Corrosion Test Structures

Isolated: Symmetric



Electrode Size
Width: 80 μm
Length: 300 μm
(Thick: 0.5 μm)
Gap: 2-10 μm

Breached: Asymmetric



Symmetric Electrodes under High Humidity and Applied Voltage

97%RH
20 hrs

+100V

-100V

→ Anodic Oxidation

Cathode
Anode

Morphology of the Corroded Electrode

2.2µm

↓ HF treatment

0.54µm

Regardless of positive or negative bias, the anode is corroded:

- Oxidation and volume expansion
- Surface film crack

rate ↑ as gap distance ↓

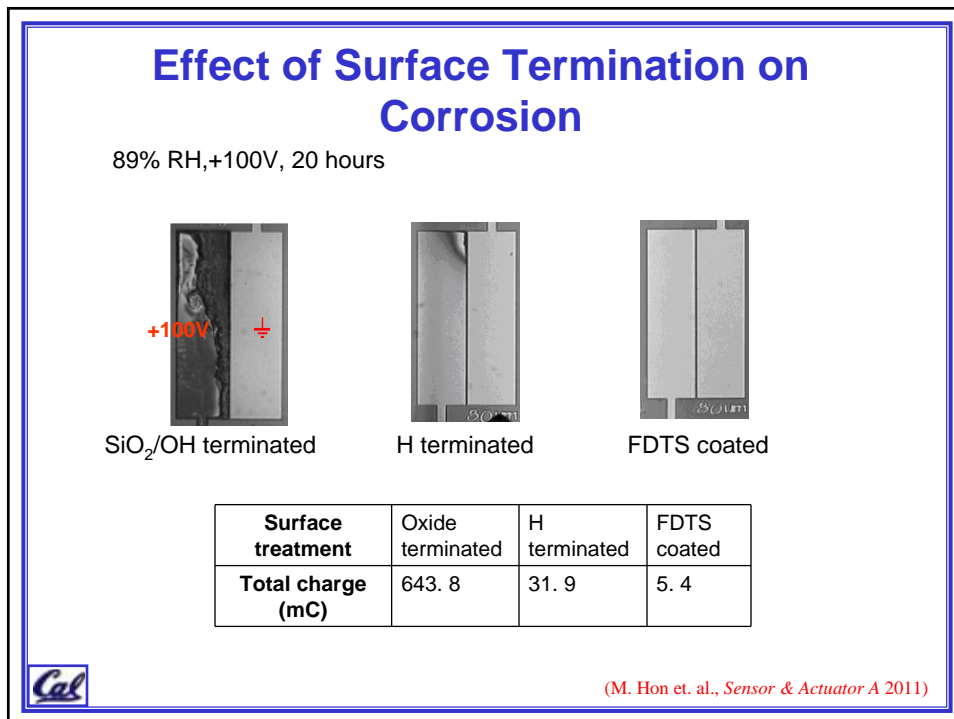
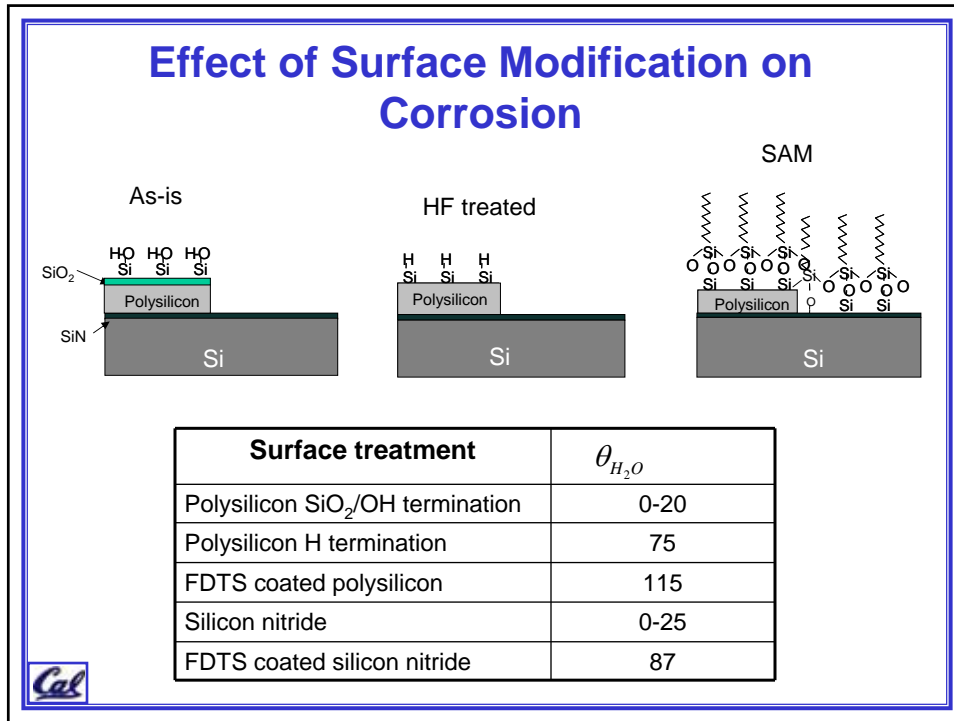
rate ↑ as voltage ↑

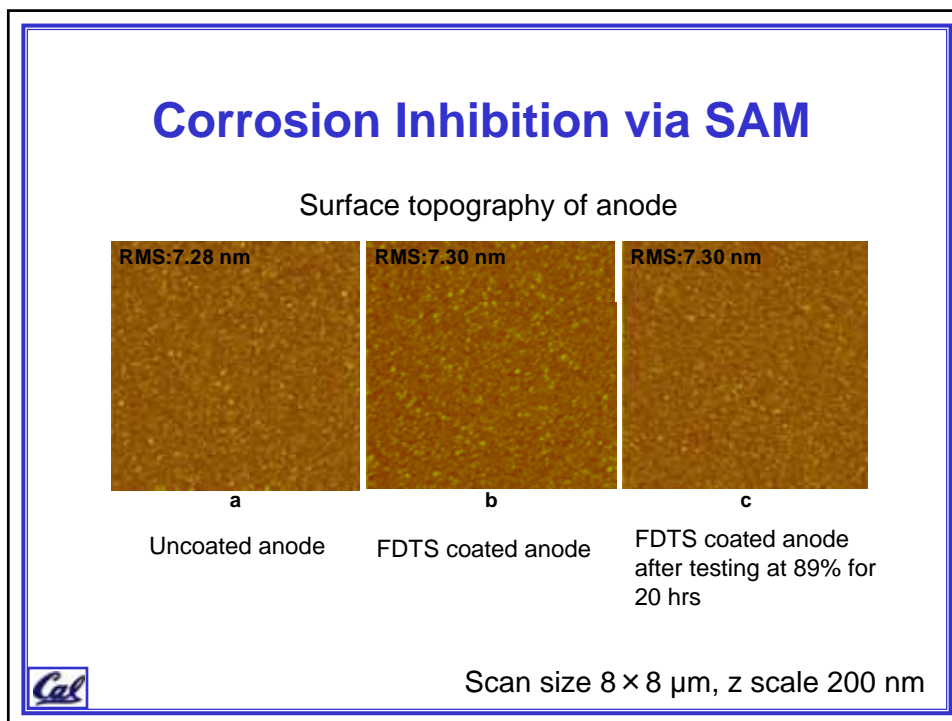
rate ↑ as RH ↑

Possible reactions at the anode:


$$H_2O \longrightarrow H^+ + OH^-$$

$$Si + 2OH^- + 2h^+ \longrightarrow SiO_2 + H_2$$



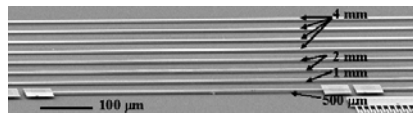
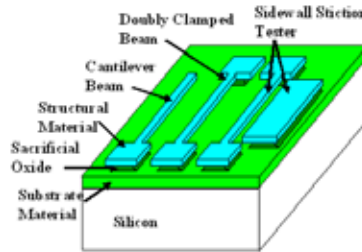


Long Term Reliability



Adhesion Characteristics of Silicon Carbide

- Significant reduction in adhesion
- 1.5 mm long beam experience no adhesion to SiC substrate whereas 200 μm beams adhere to Si substrate
- 4 mm long doubly clamped SiC beams experience no adhesion

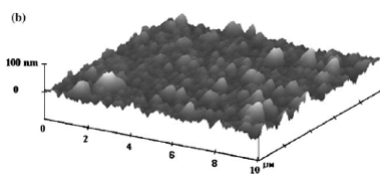
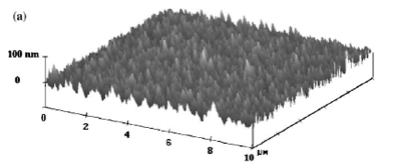


Structural Material	Substrate Material	Treatment	Cantilever Beams	
			Detachment Length (μm)	Apparent Work of Adhesion (mJ/m^2)
poly-Si	poly-Si	After release	200	20
poly-Si	SiC	After release	>1500	<0.006
		After exposed to room air for 1 week	>1500	<0.006
		After exposed to room air for 2 weeks	1000	0.034

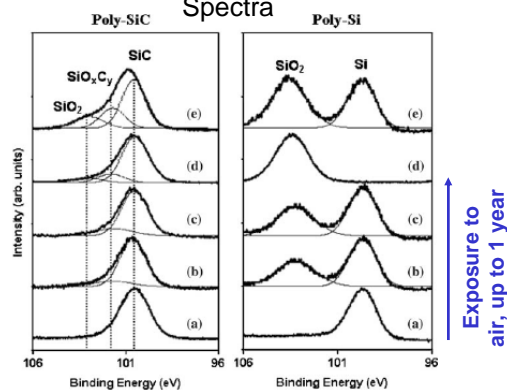


(D. Gao, *et al.*, *Tribo. Lett.* 2006)

Adhesion Characteristics of Silicon Carbide



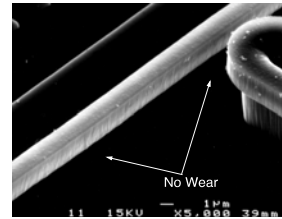
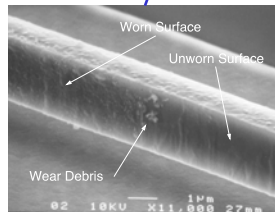
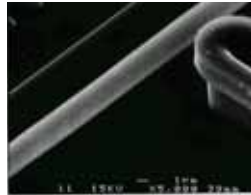
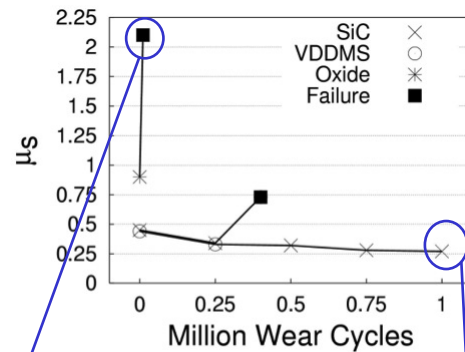
X-ray Photoelectron Spectra



- ➔
- Few points of contacts
 - High SiC hardness
 - Slow rate of SiC oxidation

Wear Characteristics of SiC Coating

- significant reduction in friction and wear with 40 nm SiC coating
- smooth operation for contact cycles exceeding 1 M cycles vs. failure for uncoated devices after 100k cycles
- friction coefficient decreases w/ contact cycles, indicating self-lubrication



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(W.R. Ashurst, et al., Tribol. Lett. 2004)

Conclusions

- MEMS-based microinstruments allow for tribological studies under conditions and materials systems of direct technological interest, and over a fundamentally interesting length scale.
- CBA analyses highlight the intriguing effect of surface chemistry and roughness on adhesion between polysilicon surfaces.
- 2AM-DC analyses suggest that the wear processes involving polysilicon surfaces may be differentiated into three phases.
- SAMs and SiC are effective in reducing the tribological challenges in MEMS technology.

